NSN 5961-01-024-5303

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View Online at https://aerobasegroup.com/nsn/5961-01-024-5303 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.170 inches and 0.210 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base 2 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Reference Number Differentiating Characteristics:** Selected item in accordance with iec dwg no. P00347103 Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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